

## SA8028

2.5 GHz sigma delta fractional-N / 760 MHz IF integer frequency synthesizers

File under Integrated Circuits - IC17

### 2.5 GHz sigma delta fractional-N / 760 MHz IF integer frequency synthesizers

## GENERAL DESCRIPTION

The SA8028 BICMOS device integrates programmable dividers, charge pumps and phase comparators to implement phase-locked loops. The device is designed to operate from 3 NiCd cells, in pocket phones, with low current and nominal 3 V supplies.
The synthesizer operates at VCO input frequencies up to 2.5 GHz . The synthesizer has fully programmable RF, IF, and reference dividers. All divider ratios are supplied via a 3-wire serial programming bus. The RF divider is a fractional-N divider with programmable integer ratios from 33 to 509 and a fractional resolution of 22 programmable bits (23 bits internal). A $2^{\text {nd }}$ order sigma-delta modulator is used to achieve fractional division.

Separate power and ground pins are provided to the charge pumps and digital circuits. $V_{\text {DDCP }}$ must be equal to or greater than $V_{D D}$. The ground pins should be externally connected to prevent large currents from flowing across the die and thus causing damage.

The charge pump current (gain) is fully programmable, while $I_{S E T}$ is set by an external resistance at the $\mathrm{R}_{\mathrm{SET}}$ pin (refer to section 1.5, RF and IF Charge Pumps). The phase/frequency detector charge pump outputs allow for implementing a passive loop filter.

## FEATURES

- Extremely low phase noise:
$\mathrm{L}_{(\mathrm{f})}=-101 \mathrm{dBc} / \mathrm{Hz}$ at 5 kHz offset at 800 MHz
- Low power
- Programmable Normal \& Integral charge pump outputs:

Maximum output $=10.4 \mathrm{~mA}$

- Digital fractional spurious compensation
- Hardware and software power-down
- $I_{\text {DDsleep }}<0.1 \mu \mathrm{~A}$ (typ) at $\mathrm{V}_{\mathrm{DD}}=3.0 \mathrm{~V}$
- Seperate supply for $V_{D D}$ and $V_{D D C P}$
- Programmable loop filter bandwidth


## APPLICATIONS

- 500 to 2500 MHz wireless equipment
- Cellular phones, all standards including:
CDMA : IS95-B,C WCDMA

3G : WCDMA / UMTS
GSM : EDGE / GPRS
TDMA : IS136 and EDGE
GAIT : GSM and TDMA

- WLAN
- Wireless PDAs
- Satellite tuners and all other high frequency equipment
- Extreme fine frequency resolution applications


SR02176
Figure 1. HBCC24 pin configuration.

## ORDERING INFORMATION

| TYPE NUMBER | PACKAGE |  |  |  |
| :--- | :--- | :--- | :--- | :--- |
|  | NAME | DESCRIPTION | VERSION |  |
| SA8028W | HBCC24 | Plastic, heatsink bottom chip carrier; 24 terminals; body $4 \times 4 \times 0.65 \mathrm{~mm}$ (CSP package) | SOT564-1 |  |

### 2.5 GHz sigma delta fractional-N /

 760 MHz IF integer frequency synthesizers
## QUICK REFERENCE DATA

$\mathrm{V}_{\mathrm{DDCP}}=\mathrm{V}_{\mathrm{DD}}=\mathrm{V}_{\mathrm{DDpre}}=+3.0 \mathrm{~V}, \mathrm{~T}_{\mathrm{amb}}=+25^{\circ} \mathrm{C}$; unless otherwise specified.

| SYMBOL | PARAMETER | CONDITIONS | MIN. | TYP. | MAX. | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{V}_{\mathrm{DD}}, \mathrm{V}_{\text {DDpre }}$ | Digital supply voltage | $\mathrm{V}_{\mathrm{DD}}=\mathrm{V}_{\text {D Dpre }}$ | 2.7 | - | 3.6 | V |
| $V_{\text {DDCP }}$ | Charge pump supply voltage | $\mathrm{V}_{\text {DDCP }} \geq \mathrm{V}_{\text {DD }}, \mathrm{V}_{\text {DDpre }}$ | 2.7 | - | 3.6 | V |
| IDDtotal | Total supply current | RF and IF. on | - | 7.6 | - | mA |
| IDDsleep | Total supply current in power-down mode |  | - | 0.1 | 1 | $\mu \mathrm{A}$ |
| $\mathrm{f}_{\text {RFin }}$ | VCO Input frequency range |  | 500 | - | 2500 | MHz |
| $\mathrm{f}_{\text {IFin }}$ | Input frequency range |  | 100 | - | 760 | MHz |
| $\mathrm{f}_{\text {REFin }}$ | Crystal reference input frequency |  | 5 | - | 30 | MHz |
| $\mathrm{f}_{\text {COMPMAX }}$ | Maximum phase comparator frequency | RF phase comparator; max. limit is indicative | - | - | 30 | MHz |
| Tamb | Operating ambient temperature |  | -40 | - | +85 | ${ }^{\circ} \mathrm{C}$ |

### 2.5 GHz sigma delta fractional-N / 760 MHz IF integer frequency synthesizers



Figure 2. HBCC24 Block Diagram

HBCC24 PIN DESCRIPTION

| SYMBOL | PIN | DESCRIPTION |
| :--- | :---: | :--- |
| V $_{\text {DDpre }}$ | 1 | Prescaler supply voltage |
| GND | 2 | Ground; digital |
| GND $_{\text {Pre }}$ | 3 | Prescaler ground; analog |
| RFin+ $^{\text {SFI }}$ | 4 | Input to RF divider (+) |
| RFin- $^{\text {GND }}$ CP | 5 | Input to RF divider (-) |
| PHP | 6 | Charge pump ground; analog |
| PHI | 7 | RF normal charge pump output |
| GND | 8 | RF integral charge pump output |
| PHA | 9 | Charge pump ground; analog |
| IFin | 10 | IF charge pump output |
| N/C | 11 | Input to IF divider |


| SYMBOL | PIN | DESCRIPTION |
| :--- | :---: | :--- |
| N/C | 13 | Not connected |
| $V_{\text {DDCP }}$ | 14 | Charge pump supply voltage; analog |
| R $_{\text {SET }}$ | 15 | External resistor from this pin to ground <br> sets the charge pump current |
| REFin- | 16 | Input to reference (-) |
| REFin+ | 17 | Input to reference (+) |
| CLOCK | 18 | Programming bus clock input |
| DATA | 19 | Programming bus data input |
| STROBE | 20 | Programming bus enable input |
| PON | 21 | Power-down control input |
| LOCK | 22 | Lock detect output |
| TEST | 23 | Test (should be either grounded or <br> connected to $\left.V_{\text {DD }}\right)$ |
| V $_{\text {DD }}$ | 24 | Supply; digital |

### 2.5 GHz sigma delta fractional-N / 760 MHz IF integer frequency synthesizers

## LIMITING VALUES

In accordance with the Absolute Maximum Rating System

| SYMBOL | PARAMETER | MIN. | MAX. | UNIT |
| :---: | :---: | :---: | :---: | :---: |
| $\mathrm{V}_{\text {DD }}$ | Digital supply voltage | -0.3 | +3.6 | V |
| $\mathrm{V}_{\text {DDCP }}$ | Charge pump supply voltage | -0.3 | +3.6 | V |
| $\mathrm{V}_{\text {DDpre }}$ | Analog supply voltage | -0.3 | +3.6 | V |
| $\Delta \mathrm{V}_{\mathrm{DD}}$ | Difference in supply voltages <br> $V_{\text {DDCP }}-V_{\text {DDpre }}\left(V_{\text {DDCP }} \geq V_{\text {DDpre }}, V_{D D}\right)$ | -0.3 | +0.9 | V |
| $\mathrm{V}_{\mathrm{n}}$ | All input pins | -0.3 | $\mathrm{V}_{\mathrm{DD}}+0.3$ | V |
| $\Delta \mathrm{V}_{\mathrm{GND}}$ | Difference in voltage between $\mathrm{GND}_{\text {pre }}, \mathrm{GND}_{\mathrm{CP}}$ and GND (these pins should be connected together) | -0.3 | +0.3 | V |
| $\mathrm{T}_{\text {stg }}$ | Storage temperature | -55 | +125 | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{T}_{\text {amb }}$ | Operating ambient temperature | -40 | +85 | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{T}_{\mathrm{j}}$ | Maximum junction temperature |  | 150 | ${ }^{\circ} \mathrm{C}$ |

## Handling

Inputs and outputs are protected against electrostatic discharge in normal handling. However, to be totally safe, it is desirable to take normal precautions appropriate to handling MOS devices.

THERMAL CHARACTERISTICS

| SYMBOL | PARAMETER | VALUE | UNIT |
| :--- | :--- | :--- | :--- |
| $R_{\text {th } j \text {-a }}$ | HBCC24: Thermal resistance from junction to ambient in still air | 30 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |

### 2.5 GHz sigma delta fractional-N /

 760 MHz IF integer frequency synthesizers
## CHARACTERISTICS

$\mathrm{V}_{\mathrm{DDCP}}=\mathrm{V}_{\mathrm{DD}}=\mathrm{V}_{\mathrm{DDpre}}=+3.0 \mathrm{~V}, \mathrm{~T}_{\mathrm{amb}}=+25^{\circ} \mathrm{C}$; unless otherwise specified.

| SYMBOL | PARAMETER | CONDITIONS | MIN. | TYP. | MAX. | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Supply |  |  |  |  |  |  |
| $V_{D D}$, <br> $V_{\text {DDpre }}$ | Digital supply voltage, prescaler supply voltage | $\mathrm{V}_{\mathrm{DD}}=\mathrm{V}_{\text {DDpre }}$ | 2.7 | - | 3.6 | V |
| $V_{\text {DDCP }}$ | Charge pump supply voltage | $\mathrm{V}_{\text {DDCP }} \geq \mathrm{V}_{\text {DD }}$, $\mathrm{V}_{\text {DDpre }}$ | 2.7 | - | 3.6 | V |
| IDDTotal | Synthesizer operational total supply current | $\mathrm{f}_{\mathrm{REF}}=20 \mathrm{MHz}$ <br> (with RF on, IF on) | - | 7.6 | - | mA |
|  |  | (with RF on, IF off) | - | 6.4 | - | mA |
| IDDsleep | Total supply current in power-down mode | logic levels 0 or VDD | - | 0.1 | 1 | $\mu \mathrm{A}$ |
| RF divider input |  |  |  |  |  |  |
| $\mathrm{f}_{\text {RFin }}$ | RF VCO input frequency range |  | 500 | - | 2500 | MHz |
| $\mathrm{V}_{\text {RFin }}$ | AC-coupled input signal level | $\mathrm{R}_{\text {in }}(\text { external })=\mathrm{R}_{\mathrm{s}}=50 \Omega ;$ single-ended drive; max. limit is indicative @ 500 to 2500 MHz | -15 | - | 0 | dBm |
|  |  |  | 112 | - | 632 | mV pp |
| $\mathrm{Z}_{\text {RFin }}$ | Input impedance Re (Z) | $\mathrm{f}_{\mathrm{RFin}}=2.4 \mathrm{GHz}$ | - | 300 | - | $\Omega$ |
| $\mathrm{C}_{\text {RFin }}$ | Typical pin input capacitance | $\mathrm{f}_{\mathrm{RFin}}=2.4 \mathrm{GHz}$ | - | 1 | - | pF |
| $\mathrm{N}_{\mathrm{RF}}$ | RF divider ratio ranges | Limited test coverage | 33 | - | 509 |  |
| FCOMPmax | Maximum phase comparator frequency | RF phase comparator | - | - | 30 | MHz |
| IF divider input |  |  |  |  |  |  |
| $\mathrm{f}_{\text {IFin }}$ | Input frequency range |  | 100 | - | 760 | MHz |
| $\mathrm{V}_{\text {IFin }}$ | AC-coupled input signal level | $\mathrm{f}_{\text {IFin: }}: 100 \mathrm{MHz}$ to 500 MHz | -15 | - | 0 | dBm |
|  |  | $\mathrm{R}_{\text {in }}(\text { external })=\mathrm{R}_{\mathrm{S}}=50 \Omega ;$ <br> max. limit is indicative | 112 | - | 632 | $\mathrm{mV}_{\mathrm{pp}}$ |
|  |  | $\begin{aligned} & \hline \mathrm{f}_{\mathrm{IFin}}: 500 \mathrm{MHz} \text { to } 760 \mathrm{MHz} \\ & \mathrm{R}_{\text {in }}(\text { external })=\mathrm{R}_{\mathrm{S}}=50 \Omega \text {; } \\ & \text { max. limit is indicative } \\ & \hline \end{aligned}$ | -10 | - | 0 | dBm |
|  |  |  | 200 | - | 632 | $\mathrm{mV}_{\mathrm{pp}}$ |
| $\mathrm{Z}_{\text {Fin }}$ | Input impedance Re (Z) | $\mathrm{f}_{\text {RFin }}=500 \mathrm{MHz}$ | - | 3.9 | - | $\mathrm{k} \Omega$ |
| $\mathrm{C}_{\text {Fin }}$ | Typical pin input capacitance | $\mathrm{f}_{\text {RFin }}=500 \mathrm{MHz}$ | - | 0.5 | - | pF |
| $\mathrm{N}_{\text {IF }}$ | IF division ratio |  | 128 | - | 16383 |  |
| Reference divider input |  |  |  |  |  |  |
| $\mathrm{f}_{\text {REFin }}$ | Input frequency range from TCXO |  | 5 | - | 30 | MHz |
| $\mathrm{V}_{\text {REFin }}$ | AC-coupled input signal level | single-ended drive; max. limit is indicative | 360 | - | 1300 | $\mathrm{mV}_{\mathrm{PP}}$ |
| $\mathrm{Z}_{\text {REFin }}$ | Input impedance Re (Z) | $\mathrm{f}_{\text {REF }}=20 \mathrm{MHz}$ | - | 10 | - | $\mathrm{k} \Omega$ |
| $\mathrm{C}_{\text {REFin }}$ | Typical pin input capacitance | $\mathrm{f}_{\text {REF }}=20 \mathrm{MHz}$ | - | 1 | - | pF |
| $\mathrm{R}_{\text {REF }}$ | Reference division ratio | SA = "000", IF loop | 4 | - | 1023 |  |
| Charge pump current setting resistor input |  |  |  |  |  |  |
| $\mathrm{R}_{\text {SET }}$ | External resistor from pin to ground |  | 6 | 7.5 | 15 | $\mathrm{k} \Omega$ |
| $\mathrm{V}_{\text {SET }}$ | Regulated voltage at pin | $\mathrm{R}_{\text {SET }}=7.5 \mathrm{k} \Omega$ | - | 1.22 | - | V |
| Charge pump outputs; $\mathrm{R}_{\mathrm{SET}}=7.5 \mathrm{k} \Omega$ |  |  |  |  |  |  |
| $\mathrm{I}_{\mathrm{CP}}$ | Charge pump current ratio to $\mathrm{ISET}^{1}$ | Current gain $=\mathrm{I}_{\mathrm{PH}} / \mathrm{I}_{\mathrm{SET}}$ | -15 | - | +15 | \% |
| $\mathrm{I}_{\text {MATCH }}$ | Sink-to-source current matching | $\mathrm{V}_{\text {PH }}=1 / 2 \mathrm{~V}_{\text {DDCP }}$ | -10 | - | +10 | \% |
| Izout | Output current variation versus $\mathrm{V}_{\mathrm{PH}}{ }^{2}$ | $\mathrm{V}_{\mathrm{PH}}$ in compliance range | -10 | - | +10 | \% |
| ILPH | Charge pump off leakage current | $\mathrm{V}_{P H}=1 / 2 \mathrm{~V}_{\text {DDCP }}$ | -10 | - | +10 | nA |
| $\mathrm{V}_{\mathrm{PH}}$ | Charge pump voltage compliance |  | 0.6 | - | $\mathrm{V}_{\text {DDCP }}-0.7$ | V |

### 2.5 GHz sigma delta fractional-N /

 760 MHz IF integer frequency synthesizers| SYMBOL | PARAMETER | CONDITIONS | MIN. | TYP. | MAX. | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Phase noise (condition $\mathrm{R}_{\text {SET }}=7.5 \mathrm{k} \Omega$, $\mathrm{CP}=00$, non speed-up mode) |  |  |  |  |  |  |
| $\mathrm{L}_{\text {(f) }}$ | Synthesizer's contribution to close-in phase noise of 900 MHz RF signal at 5 kHz offset. | $\begin{aligned} & \hline \mathrm{f}_{\text {REF }}=13 \mathrm{MHz}, \mathrm{TCXO}, \\ & \mathrm{f}_{\mathrm{COMP}}=13 \mathrm{MHz} \\ & \text { indicative, not tested } \\ & \hline \end{aligned}$ | - | -99 | - | $\mathrm{dBc} / \mathrm{Hz}$ |
|  | Synthesizer's contribution to close-in phase noise of 1800 MHz RF signal at 5 kHz offset. | As above | - | -93 | - | $\mathrm{dBc} / \mathrm{Hz}$ |
|  | Synthesizer's contribution to close-in phase noise of 800 MHz RF signal at 5 kHz offset. | $\begin{aligned} & \mathrm{f}_{\mathrm{REF}}=19.44 / 19.68 \mathrm{MHz}, \mathrm{TCXO} \\ & \mathrm{f}_{\mathrm{COMP}}=19.44 / 19.68 \mathrm{MHz} \\ & \text { indicative, not tested } \end{aligned}$ | - | -101 | - | $\mathrm{dBc} / \mathrm{Hz}$ |
|  | Synthesizer's contribution to close-in phase noise of 2100 MHz RF signal at 5 kHz offset. | As above | - | -93 | - | $\mathrm{dBc} / \mathrm{Hz}$ |
| Interface logic input signal levels |  |  |  |  |  |  |
| $\mathrm{V}_{\mathrm{IH}}$ | HIGH level input voltage |  | $0.7 * V_{\text {DD }}$ | - | $\mathrm{V}_{\mathrm{DD}}+0.3$ | V |
| $\mathrm{V}_{\mathrm{IL}}$ | LOW level input voltage |  | -0.3 | - | $0.3 * V_{\text {DD }}$ | V |
| ILEAK | Input leakage current | $\begin{aligned} & \mathrm{V}_{\mathrm{DD}}=3 \mathrm{~V}, \mathrm{~V}_{\mathrm{IH}}=3 \mathrm{~V}, \\ & \mathrm{~V}_{\mathrm{IL}}=0 \mathrm{~V} \end{aligned}$ | -0.5 | - | +0.5 | $\mu \mathrm{A}$ |
| Lock detect output signal (in push/pull mode) and Data output signal (in readout test mode) |  |  |  |  |  |  |
| $\mathrm{V}_{\text {OL }}$ | LOW level output voltage | $\mathrm{I}_{\text {sink }}=2 \mathrm{~mA}$ | - | - | 0.4 | V |
| $\mathrm{V}_{\mathrm{OH}}$ | HIGH level output voltage | $I_{\text {source }}=-2 \mathrm{~mA}$ | $\mathrm{V}_{\mathrm{DD}}-0.4$ | - | - | V |

## NOTES:

1. $I_{S E T}=\frac{V_{S E T}}{R_{S E T}}$ bias current for charge pumps.
2. The relative output current variation is defined as:

$$
\frac{\Delta I_{\text {ZOUT }}}{I_{\text {ZOUT }}}=2 \times \frac{\left(I_{2}-I_{1}\right)}{\left|I_{2}+I_{1}\right|}
$$

With $\mathrm{I}_{1} @ \mathrm{~V}_{1}=0.6 \mathrm{~V}, \mathrm{I}_{2} @ \mathrm{~V}_{2}=\mathrm{V}_{\mathrm{DDCP}}-0.7 \mathrm{~V}$ (see Figure 3).


Figure 3. Relative output current variation.

### 2.5 GHz sigma delta fractional-N / 760 MHz IF integer frequency synthesizers

### 1.0 FUNCTIONAL DESCRIPTION

Frequency synthesizers, such as Philips Semiconductors' SA8028, are a crucial part of Phase Locked Loops (PLL) for both voice and data devices used in communications. Five components make up the basic PLL (see Figure 4). A very stable, low frequency, signal source (typically a temperature controlled crystal oscillator TCXO_) is used as a reference to the system. A second signal source (typically a VCO) is used to generate the desired output frequency. A phase/frequency detector (PFD) is used to compare the phase/frequency error between the two signals. A loop filter (LPF) rejects undesired noise while also integrating the PFD output current to drive the VCO with the necessary tuning voltage, and a divider in the feedback path is used to down-convert the VCO output frequency to the reference frequency for comparison. The SA8028 is a dual synthesizer that integrates programmable dividers, programmable charge pumps and phase comparators to be implemented as part of RF and IF PLLs. The RF synthesizer operates at VCO input frequencies up to 2.5 GHz , while the IF synthesizer operates at VCO input frequencies up to 760 MHz .


Figure 4. PLL block diagram.

### 1.1 RF Fractional-N divider

The RFin inputs drive a pre-amplifier to provide the clock to the first divider stage. For single ended operation, the signal should be fed (AC-coupled) to one of the inputs while the other one is AC grounded. The pre-amplifier has a high input impedance, dominated by pin and pad capacitance. The bipolar divider is fully programmable. For allowable division ratios, see the "characteristics" table.

During each RF divider cycle, one divider output pulse is generated. The positive edge of this pulse drives the phase comparator, the negative edge drives the sigma-delta modulator which is of $2^{\text {nd }}$ order and has an effective resolution of 22 bits. Internally, the modulator works with 23 fractional bits K<22:0>, but the LSB (bit K0) is set to ' 1 ' internally to avoid limit cycles (cycles of less than maximum length). This leaves 22 bits ( $\mathrm{K}<22: 1>$ ) available for external programming.

Under these conditions (2 ${ }^{\text {nd }}$ order modulator, 23 fractional bits, $K 0=$ ' 1 '), all possible sigma-delta sequences are $2^{*} 2^{23}$ divider cycles long, which is the maximum length. The noise shaping characteristic is $+20 \mathrm{~dB} / \mathrm{dec}$ for offset frequencies up to approx. $\mathrm{f}_{\mathrm{COMP}} / 5$, which needs to be cancelled by a closed-loop transfer function of sufficient high order. The output of the sigma-delta modulator is 2 bits, which are added to the integer RF division ratio N , such that the momentary division ratios range from $(\mathrm{N}-1)$ to $(\mathrm{N}+2)$ in steps of 1 .

### 1.2 IF divider

The IFin input drives a pre-amplifier to provide the clock to the first divider stage. The pre-amplifier has a high input impedance, dominated by pin and pad capacitance. The divider consists of a fully programmable bipolar prescaler followed by a CMOS counter. The allowable divide ratios are from 128 to 16383 (C-word bits $<21: 8>$ ). Table 14 shows all the possible values that can be programmed into the C-Word for the IF divider.

### 1.3 Reference divider (see Figure 5)

The IF phase detector's reference input is an integer ratio of the reference frequency. The reference divider chain consists of a bipolar input buffer followed by a CMOS divider and a 3-bit binary counter (SA register). The allowable divide ratios, $R$, are from 4 to 1023 (B-word bits <21:12>) when the 3-bit binary counter (C-word bits $\langle 2: 0\rangle$ ) is set to all zeros, $S A=000$. The 3-bit SA register determines which of the 5 divider outputs (refer to Table 12) is selected as the IF phase detector input (see Figure 5). For the RF synthesizer, the output of the reference input buffer is routed directly (not reference divider) to the input of the RF phase detector.


Figure 5. Reference divider.

### 2.5 GHz sigma delta fractional-N / 760 MHz IF integer frequency synthesizers

### 1.4 Phase detector (see Figure 6)

The reference signal and the RF (IF) divider output are connected to a phase frequency detector that controls the charge pumps. The dead zone (caused by the finite time taken to switch the charge pump current sources on or off) is cancelled by forcing the pumps ON for a minimum time (backlash time, $\tau$ ) at every cycle providing improved linearity.


Figure 6. Phase detector structure with timing.

### 2.5 GHz sigma delta fractional-N / 760 MHz IF integer frequency synthesizers

### 1.5 RF and IF Charge Pumps

The RF phase detector drives the charge pumps on the PHP and PHI pins, while the IF phase detector drives the charge pump on the PHA pin. Both the RF and IF charge pump current values are determined by the current generated at the $\mathrm{R}_{\mathrm{SET}}$ pin ${ }^{1}$. The current gain can be further programmed by the CP0, CP1 bits in the C-word, as seen in Table 1.

## Table 1. RF and IF charge pump currents

| CP1 $^{2}$ | CP0 | $I_{\text {PHA }}$ | $I_{\text {PHP }}$ | $I_{\text {PHP-SU }}{ }^{3}$ | $I_{\text {PHI }}$ |
| :--- | :--- | :--- | :--- | :--- | :--- |
| 0 | 0 | $1.5 x I_{\text {SET }}$ | $3 x I_{\text {SET }}$ | $15 x I_{\text {SET }}$ | $36 x I_{\text {SET }}$ |
| 0 | 1 | $0.5 x I_{\text {SET }}$ | $\left.1 x\right\|_{\text {SET }}$ | $5 x I_{\text {SET }}$ | $\left.12 x\right\|_{\text {SET }}$ |
| 1 | 0 | $1.5 x I_{\text {SET }}$ | $3 x I_{\text {SET }}$ | $\left.15 x\right\|_{\text {SET }}$ | 0 |
| 1 | 1 | $0.5 x I_{\text {SET }}$ | $\left.1 x\right\|_{\text {SET }}$ | $5 x I_{\text {SET }}$ | 0 |

## NOTES

1. $\mathrm{I}_{\mathrm{SET}}=\mathrm{V}_{\mathrm{SET}} / \mathrm{R}_{\mathrm{SET}}$ : bias current for charge pumps.
2. $\mathrm{CP} 1=1$ is used to disable the PHI pump.
3. IPHP-su is the total current at pin PHP during speed up condition.

### 1.6 Charge Pumps Speed-up Mode

The RF charge pumps will enter speed-up mode when STROBE goes high after A-word has been sent. They will exit speed-up mode on the next falling edge of STROBE. There is no speed-up mode for the IF charge pump.

The charge pump, by default, will automatically go into speed-up mode (which can deliver up to $15^{*} I_{\text {SET }}$ for PHP_SU, and $36^{*} I_{\text {SET }}$ for $\mathrm{PHI})$, based on the strobe pulse width following the A-word to reduce switching speed for large tuning voltage steps (i.e., large frequency steps). Figure 7 shows the recommended passive loop filter configuration. Note: This charge pump architecture eliminates the need for added active switches and reduces external component count. Furthermore, the programmable charge pump gains provide some programmability to the loop filter bandwidth.

The duration of speed-up mode is determined by the strobe pulse that follows the A-word. Recommended optimal strobe width is equal to the total loop filter capacitance charge time from VCO control voltage level 1 to VCO control voltage level 2. The strobe width must not exceed this charge time. An external data processing unit controls the width of the strobe pulse (e.g., $\times$ number of clock cycles).

In addition, charge pumps will stay in speed-up mode continuously while Tspu = 1 (in D-word <D15>). The speed-up mode can also be disabled by programming $\mathrm{T}_{\text {dis-spu }}=1$ (in D-word $<\mathrm{D} 16>$ ).


Figure 7. Typical passive 3-pole loop filter.

### 1.7 Lock Detect

The output LOCK maintains a logic '1' when the IF phase detector (AND/ORed) with the RF phase detector indicates a lock condition. The lock condition for the RF and IF synthesizers is defined as a phase difference of less than $\pm 1$ period of the frequency at the input $R E F_{i n+}, R E F_{\text {in_- }}$. One counter can fulfill the lock condition when the other counter is powered down. Out of lock (logic ' 0 ') is indicated when both counters are powered down.

### 1.8 Power-down mode

With power applied to the chip, power-down mode can be entered either by hardware (external signal on pin PON) or by software (by programming the PD = Power Down bits (<B10, B9>) in the B-word). The PON signal is exclusively ORed with the PD bits. If $\mathrm{PON}=0$, then the part is powered up when $\mathrm{PD}=1$ (<B10, B9>). PON can be used to invert the polarity of the software bits PD. Table 9 of section 2.4.2 illustrates how power-down mode can be implemented.

During power-down mode the 3-wire bus remains active and programming-words may be pre-loaded before switching to power-up mode. If the chip is programmed while in power-down mode, the RF divider ratio $N_{R F}$ is internally presented to the RF divider on the next falling edge of STROBE after STROBE has gone high at the end of the A-word. Power-down mode does not reset the sigma-delta modulator., i.e., power-down mode preserves the state of the sigma-delta modulator (as long as power is applied to the chip).

To take advantage of the register pre-loading capability while the device is in power-down mode, the B-word needs to be sent a second time (i.e., again, after the A-word), with the PD (<B10, B9>) bits now programmed for power-up.

If power-up mode is to be controlled by hardware, the PON signal must be toggled only after the A-word has been sent and STROBE has gone high and then low.
When the synthesizer is reactivated after power-down mode, the IF and reference dividers are synchronized to avoid random phase errors on power-up. There is no power-up synchronization between the RF divider and the reference clock. After power-up, there is a delay of four edges (i.e. 1.5 cycles) of the output clock of the reference divider before the RF phase detector is activated. That means the reference divider must be powered up for the RF phase detector to become active.

When initially applying or reapplying power to the chip, and internal power-up reset pulse is generated which sets the programming-words to their default values and also resets the sigma-delta modulator to its "all-0" state. It is also recommended that the D-word be manually reset to all zeros, following initial power-up, to avoid unknown states.

### 2.5 GHz sigma delta fractional-N / 760 MHz IF integer frequency synthesizers

### 2.0 SERIAL PROGRAMMING BUS

A simple 3-line bidirectional serial bus is used to program the circuit. The 3 lines are DATA, CLOCK and STROBE. When the STROBE $=0$, the clock driver is enabled and on the positive edges of the CLOCK signal, DATA is clocked into temporary shift registers. When the STROBE $=1$, the clock is disabled and the data in the shift register is latched into different working registers, depending on the address bits. In order to fully program the circuit, 3 words must be sent in the following order: $\mathrm{C}, \mathrm{B}$, and A . An additional word, the D-word, is for test purposes only: all bits in this test word should be initialized to 0 for normal operation. The N value of the B -word is stored temporarily until the A-word is loaded to avoid temporarily false N settings, while the corresponding fractional ratio Kn is not yet active. When a new fractional ratio is loaded through the A-word, the fractional sigma delta modulator is not reset, i.e., it will start the new fractional sequence from the last state of the previously executed sequence. A typical programming sequence is illustrated in Figure 10.

When loading several words in series, the minimum STROBE high time between words must be observed (refer to Figure 8).
Unlike the earlier SA80xx family members, SA8028 has the built-in feature to output the contents of an addressable internal register. For the current SA8028, only the momentary division ratio $N$ (RF divider) can be retrieved through the serial bus. The handshake protocol requires a "request to read" to be sent prior to each "read", i.e., by sending a D-word with the TreadN-bit (<D11>) set to "high". Immediately after the transition of "STROBE" from low-to-high, four (4) clock pulses are needed to prepare the data for output and another nine (9) clock pulses are needed to accomplish the serial reading with LSB first. A high-to-low transition of "STROBE" then resets the serial bus to the input mode. The timing diagram is presented in Figure 9. In general, a high-to-low transition of the "STROBE" signal will instantaneously reset the serial bus to the input mode, even when the chip is in the output mode.

Table 2. Serial bus timing requirements (see Figures 8 and 9)
$V_{D D}=V_{D D C P}=+3.0 \mathrm{~V} ; T_{\text {amb }}=+25^{\circ} \mathrm{C}$ unless otherwise specified. (Guaranteed by design.)

| SYMBOL | PARAMETER | MIN. | TYP. | MAX. | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: |
| Serial programming clock; CLK |  |  |  |  |  |
| $\mathrm{t}_{\mathrm{r}}$ | Input rise time | - | 10 | 40 | ns |
| $\mathrm{t}_{\mathrm{f}}$ | Input fall time | - | 10 | 40 | ns |
| $\mathrm{T}_{\text {cy }}$ | Clock period | 100 | - | - | ns |
| Enable programming; STROBE |  |  |  |  |  |
| $\mathrm{t}_{\text {START, }} \mathrm{I}_{\text {START; }}$ | Delay to rising clock edge | 40 | - | - | ns |
| $t_{W}$ | Minimum inactive pulse width | 1/fCOMP | - | - | ns |
| $\mathrm{t}_{\text {SU; }}$ | Enable set-up time to next clock edge | 20 | - | - | ns |
| $t_{\text {RESET }}$ | Reset data line to input mode | 20 | - | - | ns |
| Register serial input data; DATA (I) |  |  |  |  |  |
| $\mathrm{t}_{\text {SU; }}$ DAT | Input data to clock set-up time | 20 | - | - | ns |
| $\mathrm{t}_{\mathrm{HD} ; \text { DAT }}$ | Input data to clock hold time | 20 | - | - | ns |
| Register serial output data; DATA (0) |  |  |  |  |  |
| tsu;DAT;R | Input clock to data set-up time | 20 | - | - | ns |
| CLK <br> DATA <br> STROBE |  | TCY | BESS |  | 2296 |

Figure 8. Serial bus "Write" timing diagram.

### 2.5 GHz sigma delta fractional-N / 760 MHz IF integer frequency synthesizers



Figure 9. Serial bus "Read" timing diagram.

### 2.5 GHz sigma delta fractional-N / 760 MHz IF integer frequency synthesizers



Figure 10. Typical programming sequence

### 2.5 GHz sigma delta fractional-N /

 760 MHz IF integer frequency synthesizers
### 2.1 Data format

Each of the 4 word registers contains 24 programmable bits. Data is serially clocked in on the rising edge of each clock pulse with the LSB first in, and MSB last in.

Table 3. Format of programmed data

| LAST IN | SERIAL PROGRAMMING FORMAT |  |  |  |  |  | FIRST IN |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| p23 | p22 | p21 | p20 | .. / .. | .. $/ .$. | p1 | p0 |

### 2.2 Register addressing

Table 4. Register addressing

| Bit | <23> | <22> | <21> |
| :---: | :---: | :---: | :---: |
| A-word address | 0 | 0 | x |
| B-word address | 0 | 1 | x |
| C-word address | 1 | 0 | x |
| D-word address | 1 | 1 | 0 |

Notice that the register addresses are the MSB in each word; thus, the last to be clocked into the registers.

### 2.3 A-word register

Table 5. A-word, length 24 bits

| Last IN |  | <21> | <20> | <19> | <18> | <17> | <16> | <15> | <14> | <13> | <12> | <11> | <10> | <9> | <8> | <7> | <6> | <5> | <4> | <3> | <2> | <1> | <0> |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Address |  | Fractional ratio Kn |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |
| 0 | 0 | K22 | K21 | K20 | K19 | K18 | K17 | K16 | K15 | K14 | K13 | K12 | K11 | K10 | K9 | K8 | K7 | K6 | K5 | K4 | K3 | K2 | K1 |
| Default : |  | 0 | 0 | 0 | 0 | 1 | 1 | 0 | 1 | 0 | 1 | 1 | 0 | 1 | 1 | 1 | 0 | 1 | 0 | 0 | 1 | 1 | 1 |
| A word address |  |  |  |  | Fixed to 00. |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |
| Fractional ratio select |  |  |  |  | Kn sets the fractional part of the total division ratio. To avoid limit cycles the K0 bit is internally set to "1" |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |

### 2.3.1 The fractional multiplier [A21:A0](A21:A0)

The A-word register is dedicated for programming the RF loop, fractional multiplier (the sigma-delta modulator) which has an effective resolution of 22 bits. The modulator works with 23 bits, $\mathrm{Kn}<22: 0>$. However, this KO bit is set to ' 1 ' internally to avoid limit cycles (cycles of less than maximum length). This leaves 22 bits ( $\mathrm{Kn}<22: 1>$ ) available for external programming. Refer to Table 6.
Calculating the desired VCO output frequency can be easily accomplished by using the following equation, Equation (1).

$$
\begin{equation*}
f_{V C O}=f_{r e f}\left(N+\frac{2 \times K n<22: 1>+1}{2^{23}}\right) \tag{1}
\end{equation*}
$$

where $f_{\text {ref }}$ is the reference frequency at the REF input pin and $N$ is the integer multiplier. $K_{n}$, once again, is the fractional multiplier.

## Example:

Determine the Kn value required for generating a VCO frequency of 2100 MHz with a reference frequency of 19.68 MHz .

$$
\begin{aligned}
K n<22: 1> & =\frac{\left[\left(\frac{f_{V C O}}{f_{r e f}}-N\right) \times 2^{23}\right]}{2} \\
K n<22: 1> & =\frac{\left[\left(\frac{2100 \mathrm{MHz}}{19.68 \mathrm{MHz}}-106\right) \times 2^{23}\right]}{2}=2966702
\end{aligned}
$$

### 2.5 GHz sigma delta fractional-N /

 760 MHz IF integer frequency synthesizersTable 6. Kn values for the fractional divider

| $\langle\mathrm{A} 21\rangle$ | $\langle\mathrm{A} 20\rangle$ | $\langle\mathrm{A} 19\rangle$ | $\langle\mathrm{A} 18\rangle$ | $\langle\mathrm{A} 17\rangle$ | $\langle\mathrm{A} 16\rangle$ | $\langle\mathrm{A} 15\rangle$ | $\langle\mathrm{A} 14\rangle$ | $\langle\mathrm{A} 13\rangle$ | $\langle\mathrm{A} 12\rangle$ | $\langle\mathrm{A} 11\rangle$ | $\langle\mathrm{A} 10\rangle$ | $\langle\mathrm{A} 9\rangle$ | $\langle\mathrm{A} 8\rangle$ | $\langle\mathrm{A} 7\rangle$ | $\langle\mathrm{A} 6\rangle$ | $\langle\mathrm{A} 5\rangle$ | $\langle\mathrm{A} 4\rangle$ | $\langle\mathrm{A} 3\rangle$ | $\langle\mathrm{A} 2\rangle$ | $\langle\mathrm{A} 1\rangle$ | $\langle\mathrm{A} 0\rangle$ | Kn |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 1 | 1 |
| 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 1 | 0 | 2 |
| 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 1 | 1 | 3 |
| 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 1 | 0 | 0 | 4 |
| - | - | - | - | - | - | - | - | - | - | - | - | - | - | - | - | - | - | - | - | - | - | $\ldots$ |
| 1 | 0 | 1 | 1 | 0 | 1 | 0 | 1 | 0 | 0 | 0 | 1 | 0 | 0 | 1 | 0 | 1 | 0 | 1 | 1 | 1 | 0 | 2966702 |
| - | - | - | - | - | - | - | - | - | - | - | - | - | - | - | - | - | - | - | - | - | - | $\ldots$ |
| 1 | 1 | 1 | 1 | 1 | 1 | 1 | 1 | 1 | 1 | 1 | 1 | 1 | 1 | 1 | 1 | 1 | 1 | 1 | 1 | 1 | 0 | 4194302 |
| 1 | 1 | 1 | 1 | 1 | 1 | 1 | 1 | 1 | 1 | 1 | 1 | 1 | 1 | 1 | 1 | 1 | 1 | 1 | 1 | 1 | 1 | 4194303 |

### 2.4 B-word register

Table 7. B-word, length 24 bits

| Last IN |  | <21> | <20> | <19> | <18> | <17> | <16> | <15> | <14> | <13> | <12> | <11> | <10> | <9> | <8> | <7> | <6> | <5> | <4> | <3> | <2> | <1> | <0> |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Address |  | Reference divider ratio Rn |  |  |  |  |  |  |  |  |  | Reset bit | Power Down |  | RF Divider integer ratio N |  |  |  |  |  |  |  |  |
| 0 | 1 | R9 | R8 | R7 | R6 | R5 | R4 | R3 | R2 | R1 | R0 | PDref | IF | RF | N8 | N7 | N6 | N5 | N4 | N3 | N2 | N1 | N0 |
| Default: |  | 0 | 0 | 0 | 1 | 0 | 1 | 0 | 0 | 0 | 1 | 0 | 1 | 1 | 0 | 0 | 1 | 1 | 0 | 1 | 1 | 0 | 0 |
| B-word address |  |  |  |  | Fixed to 01 |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |
| R-Divider |  |  |  |  | R0..R9, Reference divider values, see section "characteristics" for allowed divider ratios. |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |
| Reset bit |  |  |  |  | $1 \rightarrow$ Pdref : powers down (=resets) the reference divider |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |
| Power-down |  |  |  |  | See Truth Table 9 |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |
| N -Divider |  |  |  |  | Nn sets the integer part of the RF divider ratio, see section "characteristics" for allowed ratios. |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |

### 2.4.1 The RF divider [B8:B0](B8:B0)

Programming the RF divider to obtain the desired VCO output frequency is done by programming the B-word followed by the A-word. The integer divider bits $\mathrm{N}<8: 0>$ are in the B -word, whereas the fractional divider bits $\mathrm{Kn}<22: 1>$ are in the A -word. Allowable integer division ratios are shown in Table 8. The N value, from Equation (2), is simply the whole number of times the reference frequency goes into the desired VCO output frequency. Recall that the reference frequency for the RF loop is not reduced prior to the phase detector. In other words, the frequency at the input of the REFin is the comparison frequency.

$$
\begin{align*}
& N=\frac{f_{V C O}}{f_{\text {ref }}}-\frac{M O D U L O\left(\frac{f_{V C O}}{f_{\text {ref }}}\right)}{f_{\text {ref }}}  \tag{2}\\
& N=\frac{900 \mathrm{MHz}}{19.68 \mathrm{MHz}}-\frac{M O D U L O\left(\frac{900 \mathrm{MHz}}{19.68 \mathrm{MHz}}\right)}{19.68 \mathrm{MHz}} \\
& N=45.7317073170 \ldots-\frac{14.4}{19.68}=45
\end{align*}
$$

### 2.5 GHz sigma delta fractional-N /

 760 MHz IF integer frequency synthesizersTable 8. Allowable integer values ( N ) for the RF divider

| <B8> | <B7> | <B6> | <B5> | <B4> | <B3> | <B2> | <B1> | <B0> | N |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| 0 | 0 | 0 | 1 | 0 | 0 | 0 | 0 | 1 | 33 |
| - | - | - | - | - | - | - | - | - | $\ldots$ |
| - | - | - | - | - | - | - | - | - | $\ldots$ |
| - | - | - | - | - | - | - | - | - | $\ldots$ |
| - | - | - | - | - | - | - | - | - | $\cdots$ |
| 1 | 1 | 1 | 1 | 1 | 1 | 1 | 0 | 1 | 509 |

### 2.4.2 Power-down [B10:B9](B10:B9)

If the chip is programmed while in power-up mode, the loading of the A-word and of the N values in the B-word are synchronized to the RF divider output pulse. The data takes effect internally on the second falling edge of the RF divider output pulse after STROBE has gone high at the end of the A-word. STROBE does not need to be held high until that second falling edge of the RF divider output pulse has occurred.

If the chip is programmed while in power-down mode, this synchronization scheme is disabled. The fully static CMOS design uses virtually no current when the bus is inactive. It can always capture new programmed data, even during power-down.

To take advantage of the program register pre-loading capability while the device is in power-down mode, the B-word needs to be sent a second time (i.e. again, after the A-word), with the PD bits now programmed for power-up. If power-up mode is to be controlled by hardware, the PON signal must be toggled only after the A-word has been sent and STROBE has gone high and then low.

When the synthesizer is reactivated after power-down mode, the IF and reference dividers are synchronized to avoid random phase errors on power-up. There is no power-up synchronization between the RF divider and the reference clock. However, after power-up, there is a delay of four edges (i.e. 1.5 cycles) of the output clock of the reference divider before the RF phase detector is activated. That means the reference divider must be powered up for the RF phase detector to become active.

When initially applying or re-applying power to the chip, an internal power-up reset pulse is generated which sets the programming-words to their default values and also resets the sigma-delta modulator to its "all-0" state. It is also recommended that the D-word be manually reset to all zeros, following initial power-up, to avoid unknown states.

Table 9. Power-down Truth Table

| PON | IF <br> <B10> | RF <br> <B9> | IF | RF |
| :---: | :---: | :---: | :---: | :---: |
| 0 | 0 | 0 | OFF | OFF |
| 0 | 0 | 1 | OFF | ON |
| 0 | 1 | 0 | ON | OFF |
| 0 | 1 | 1 | ON | ON |
| 1 | 0 | 0 | ON | ON |
| 1 | 0 | 1 | ON | OFF |
| 1 | 1 | 0 | OFF | ON |
| 1 | 1 | 1 | OFF | OFF |

### 2.5 GHz sigma delta fractional-N / 760 MHz IF integer frequency synthesizers

### 2.4.3 Programming the IF Reference Divider [B21:B12](B21:B12)

The IF phase detector's reference input is an integer multiple of the frequency at the input of the REFin pin. The reference divider has 10 programmable bits, [B21:B12](B21:B12) for allowable divide ratios, R, from 4 to 1023 when the 3 bit binary SA counter (refer to section 2.5 .1 ) is set to all zeros. Table 10 lists the allowable R values.

Table 10. R Values for the IF Reference Divider

| <B21> | <B20> | <B19> | <B18> | <B17> | <B16> | <B15> | <B14> | <B13> | <B12> | R |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| 0 | 0 | 0 | 0 | 0 | 0 | 0 | 1 | 0 | 0 | 4 |
| 0 | 0 | 0 | 0 | 0 | 0 | 0 | 1 | 0 | 1 | 5 |
| 0 | 0 | 0 | 0 | 0 | 0 | 0 | 1 | 1 | 0 | 6 |
| - | - | - | - | - | - | - | - | - | - | $\ldots$ |
| 1 | 1 | 1 | 1 | 1 | 1 | 1 | 1 | 1 | 0 | 1022 |
| 1 | 1 | 1 | 1 | 1 | 1 | 1 | 1 | 1 | 1 | 1023 |

### 2.5 C-word Register

Table 11. C-word, length 24 bits

| Last IN | <21> | <20> | <19> | <18> | <17> | <16> | <15> | <14> | <13> | <12> | <11> | <10> | <9> | <8> | <7> | <6> | <5> | <4> | <3> | <2> | <1> | <0> |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Address | IF Divider An |  |  |  |  |  |  |  |  |  |  |  |  |  | CP |  | Lock detect |  | Reset bit | SA |  |  |
| $1{ }^{1}$ | A13 | A12 | A11 | A10 | A9 | A8 | A7 | A6 | A5 | A4 | A3 | A2 | A1 | A0 | CP1 | CP0 | L1 | L0 | Tsigrst | SA2 | SA1 | SA0 |
| Default: | 0 | 0 | 0 | 0 | 0 | 1 | 1 | 1 | 0 | 0 | 1 | 0 | 1 | 0 | 1 | 1 | 0 | 0 | 0 | 0 | 0 | 0 |
| C-word address |  |  |  | Fixed to 10 |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |
| A-Divider |  |  |  | A0..A13, IF divider values, see section "characteristics for allowed for divider ratios. |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |
| Charge pump current Ratio |  |  |  | CP1, CP0: Charge pump current ratio, see table of charge pump currents. |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |
| Lock detect |  |  |  | See Table 13. |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |
| Reset bit |  |  |  | $1 \rightarrow$ Tsigrst : resets the sigma-delta modulator after each loading of an A-word. <br> ( It is held in the reset state between the first and second falling edge of the RF divider output pulse after STROBE has gone high at the end of the A-word. ) |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |
| IF comparison select |  |  |  | SA Comparison divider select for IF phase detector |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |

### 2.5.1 Programming the SA Counter [C2:C0](C2:C0)

The 3 bit SA register determines which of the 5 divider outputs (refer to table 11) is selected as the IF phase detector's input (see Figure 5 ).
Table 12. IF phase comparator frequency

| <C2> | <C1> | <C0> | Divide Ratio | IF Phase Comparator Frequency |
| :---: | :---: | :---: | :---: | :---: |
| 0 | 0 | 0 | R | $\mathrm{f}_{\text {ref }} 1 / \mathrm{R}$ |
| 0 | 0 | 1 | $\mathrm{R} * 2$ | $\mathrm{f}_{\text {ref }} /(\mathrm{R} * 2)$ |
| 0 | 1 | 0 | $\mathrm{R} * 4$ | $\mathrm{f}_{\text {ref }} /(\mathrm{R} * 4)$ |
| 0 | 1 | 1 | $\mathrm{R} * 8$ | $\mathrm{f}_{\mathrm{ref}} /(\mathrm{R} * 8)$ |
| 1 | 0 | 0 | $\mathrm{R} * 16$ | $\mathrm{f}_{\text {ref }} /(\mathrm{R} * 16)$ |

## NOTES:

1. $f_{\text {ref }}$ is the input frequency at the REFin pin.

### 2.5.2 Programming the Reset Bits <B11>, <C3>

The reset bits offer extra flexibility. The default value for bits <B11>, <C3> are all zeros. Bit <B11> disables the IF reference divider and allows for extra savings of approximately $200 \mu \mathrm{~A}$ when set to ' 1 '. However, this bit must initially be set to ' 0 ' during any power-up sequence. The RF phase detector is activated after a delay of four edges of the reference divider output clock. Bit <C3> resets the sigma-delta modulator after each loading of an A-word. It is held in the reset state between the first and second falling edge of the RF divider output pulse after STROBE has gone high at the end of the A-word.

### 2.5 GHz sigma delta fractional-N /

 760 MHz IF integer frequency synthesizers
### 2.5.3 Programming the Lock Detect [C4:C5](C4:C5)

Lock detection is available only for the RF and IF phase detector. A ' 0 ' in bit [C4:C5](C4:C5) is used for TTL, while a ' 1 ' in bit $<C 4$ :C5> is used for RTL.
Table 13. Lock detect select

| L1 | L0 | Select |
| :--- | :--- | :--- |
| 0 | 0 | RF/IF (push/pull) $)^{1}$ |
| 0 | 1 | RF/IF (open drain) |
| 1 | 0 | RF (push/pull) |
| 1 | 1 | IF (push/pull) |

## NOTE:

1. Combined RF_IF lock detect signal present at the lock pin (push/pull).

### 2.5.4 Programming the Charge Pump Gain [C7:C6](C7:C6)

The RF phase detector drives the charge pumps on the PHP and PHI pins, while the IF phase detector drives the charge pump on the PHA pin. The current generated at the $R_{\text {SET }}$ pin determines both the RF and IF charge pump current values in conjunction with the current gain programmed by the CP0, CP1 bits in the C-word, as seen in Table 1. For more information on charge pump speed-up mode, refer to section 1.6.

### 2.5.5 Programming the IF Divider for the IF Loop [C21:C8](C21:C8)

The divider is a fully programmable counter. The allowable divide ratios, A, are from 128 to 16383 , bits [C21:C8](C21:C8). Table 14 shows all the possible values that can be programmed into the C-word for the IF divider.
Table 14. Allowable Values (A) for the IF Divider

| C21 | C20 | C19 | C18 | C17 | C16 | C15 | C14 | C13 | C12 | C11 | C10 | C9 | C8 | A |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| 0 | 0 | 0 | 0 | 0 | 0 | 1 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 128 |
| 0 | 0 | 0 | 0 | 0 | 0 | 1 | 0 | 0 | 0 | 0 | 0 | 0 | 1 | 129 |
| 0 | 0 | 0 | 0 | 0 | 0 | 1 | 0 | 0 | 0 | 0 | 0 | 1 | 0 | 130 |
| - | - | - | - | - | - | - | - | - | - | - | - | - | - | $\ldots$ |
| 1 | 1 | 1 | 1 | 1 | 1 | 1 | 1 | 1 | 1 | 1 | 1 | 1 | 0 | 16382 |
| 1 | 1 | 1 | 1 | 1 | 1 | 1 | 1 | 1 | 1 | 1 | 1 | 1 | 1 | 16383 |

### 2.6 D-word Register

The D-word is for test purposes only. All bits in this test word should be initialized to 0 for normal operation. When initially applying or re-applying power to the chip, an internal power-up reset pulse if generated which sets the programming-words to their default values and which resets the sigma-delta modulator to its "all-0" state. It is also recommended that the D-word be manually reset to all zeros, following initial power-up, to avoid unknown states.
Table 15. D-word, length 24 bits

| Last IN | <21> | <20> | <19> | <18> | <17> | <16> | <15> | <14> | <13> | <12> | <11> | <10> | <9> | <8> | <7> | <6> | <5> | <4> | <3> | <2> | <1> | <0> |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Address |  | Synthesizer Test bits |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |
| $1{ }^{1}$ | 0 | - | - | - | - | Tdis-spu | Tspu | - | - | - | TreadN | - | - | - | - | - | - | - | - | - | - | - |
| Default |  | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 |
| D word address |  |  |  |  | Fixed to 110. |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |
| Tdis-spu |  |  |  |  | Speed-up mode disabled. |  |  |  |  | NOTE: All other test bits must be set to 0 for normal operation. |  |  |  |  |  |  |  |  |  |  |  |  |
| Tspu: Speed up |  |  |  |  | Speed-up mode always on. NOTE: All other test bits must be set to 0 for normal operation. |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |
| TreadN |  |  |  |  | Used to "request to read" bit settings from bits [B21:12](B21:12). For more information on reading out the N value, refer to Section 2.0, Serial Programming Bus. |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |

### 2.5 GHz sigma delta fractional-N / 760 MHz IF integer frequency synthesizers

### 3.0 Typical Performance Characteristics



Figure 11. PHI_SU charge pump output vs. Iset ( $\mathrm{CP}=01 \_12 \mathrm{x}, \mathrm{V}_{\mathrm{DD}}=3.0 \mathrm{~V}$, Temp $=25^{\circ} \mathrm{C}$ )


Figure 13. PHI_SU charge pump output vs. Iset ( $\mathrm{CP}=00 \_36 \mathrm{x}, \mathrm{V}_{\mathrm{DD}}=3.0 \mathrm{~V}$, Temp $=25^{\circ} \mathrm{C}$ )


Figure 12. PHI_SU charge pump output vs. temperature ( $C P=01 \_12 x, V_{D D}=3.0 \mathrm{~V}$, Iset $\left.=163 \mu \mathrm{~A}\right)$


Figure 14. PHI_SU charge pump output vs. temperature ( $C P=00 \_36 x, V_{D D}=3.0 \mathrm{~V}$, Iset $=163 \mu \mathrm{~A}$ )

### 2.5 GHz sigma delta fractional-N / 760 MHz IF integer frequency synthesizers



Figure 15. PHP charge pump output vs. Iset
(CP = 10_3x, $\mathrm{V}_{\mathrm{DD}}=3.0 \mathrm{~V}$, Temp $=25^{\circ} \mathrm{C}$ )


Figure 17. PHP charge pump output vs. Iset (CP = 11_1x, $\mathrm{V}_{\mathrm{DD}}=3.0 \mathrm{~V}$, Temp $=25^{\circ} \mathrm{C}$ )


Figure 16. PHP charge pump output vs. temperature ( $C P=10 \_3 x, V_{D D}=3.0 \mathrm{~V}$, Iset $=163 \mu \mathrm{~A}$ )


Figure 18. PHP charge pump output vs. temperature ( $C P=11 \_1 x, V_{D D}=3.0 \mathrm{~V}$, Iset $=163 \mu \mathrm{~A}$ )

### 2.5 GHz sigma delta fractional-N / 760 MHz IF integer frequency synthesizers



Figure 19. PHP_SU charge pump output vs. Iset (CP = 01_5x, $\mathrm{V}_{\mathrm{DD}}=3.0 \mathrm{~V}$, Temp $=25^{\circ} \mathrm{C}$ )


Figure 21. PHP_SU charge pump output vs. Iset ( $\mathrm{CP}=00 \_15 \mathrm{x}, \mathrm{V}_{\mathrm{DD}}=3.0 \mathrm{~V}, \mathrm{Temp}=25^{\circ} \mathrm{C}$ )


Figure 20. PHP_SU charge pump output vs. temperature $\left(C P=01 \_5 x, V_{D D}=3.0 \mathrm{~V}\right.$, Iset $\left.=163 \mu \mathrm{~A}\right)$


Figure 22. PHP_SU charge pump output vs. temperature ( $\mathrm{CP}=00 \_15 \mathrm{x}, \mathrm{V}_{\mathrm{DD}}=3.0 \mathrm{~V}$, Iset $=163 \mu \mathrm{~A}$ )

### 2.5 GHz sigma delta fractional-N /

 760 MHz IF integer frequency synthesizers

Figure 23. PHA charge pump output vs. Iset ( $\mathrm{CP}=11 \_0.5 \mathrm{x}, \mathrm{V}_{\mathrm{DD}}=3.0 \mathrm{~V}$, Temp $=25^{\circ} \mathrm{C}$ )


Figure 25. PHA charge pump output vs. Iset ( $\mathrm{CP}=10 \_1.5 \mathrm{x}, \mathrm{V}_{\mathrm{DD}}=3.0 \mathrm{~V}, \mathrm{Temp}=25^{\circ} \mathrm{C}$ )


Figure 24. PHA charge pump output vs. temperature ( $C P=11 \_0.5 x, V_{D D}=3.0 \mathrm{~V}$, Iset $=163 \mu \mathrm{~A}$ )


Figure 26. PHA charge pump output vs. temperature $\left(C P=10 \_1.5 x, V_{D D}=3.0 \mathrm{~V}\right.$, Iset $\left.=163 \mu \mathrm{~A}\right)$

### 2.5 GHz sigma delta fractional-N /

 760 MHz IF integer frequency synthesizers

Figure 27. RF (main) divider input sensitivity vs. frequency and supply voltage (Temp $=25^{\circ} \mathrm{C}$, Iset $=164 \mu \mathrm{~A}, \mathrm{~N}=509$ )


Figure 29. RF (main) fractional divider input sensitivity vs. frequency and supply voltage (Temp $=25^{\circ} \mathrm{C}$, Iset $=164 \mu \mathrm{~A}$, $\mathrm{N}=509.5$ )


Figure 31. IF (aux) divider input sensitivity vs. frequency and supply voltage (Temp $=25^{\circ} \mathrm{C}$, Iset $=164 \mu \mathrm{~A}$, divider ratio $=16383$ )


Figure 28. RF (main) divider input sensitivity vs. frequency and temperature ( $\mathrm{V}_{\mathrm{CC}}=3.0 \mathrm{~V}$, Iset $=164 \mu \mathrm{~A}, \mathrm{~N}=509$ )


Figure 30. RF (main) fractional divider input sensitivity vs. frequency and temperature ( $\mathrm{V}_{\mathrm{CC}}=3.0 \mathrm{~V}$, Iset $=164 \mu \mathrm{~A}$, $\mathrm{N}=509.5$ )


Figure 32. IF (aux) divider input sensitivity vs. frequency and temperature $\left(\mathrm{V}_{\mathrm{CC}}=3.0 \mathrm{~V}\right.$, Iset $=164 \mu \mathrm{~A}$, divider ratio $=16383$ )

### 2.5 GHz sigma delta fractional-N /

 760 MHz IF integer frequency synthesizers

Figure 33. Reference divider input sensitivity vs. frequency and supply voltage ( $\mathrm{Temp}=25^{\circ} \mathrm{C}$, Iset $=164 \mu \mathrm{~A}$, divider ratio $=1023$ )


Figure 35. Total supply current vs. temperature (Iset $=163 \mu \mathrm{~A}$ Fcomp $=\mathbf{2 0} \mathrm{MHz}$ )


Figure 34. Reference divider input sensitivity vs. frequency and temperature $\left(\mathrm{V}_{\mathrm{CC}}=3.0 \mathrm{~V}\right.$, Iset $=164 \mu \mathrm{~A}$, divider ratio $=1023$ )

### 2.5 GHz sigma delta fractional-N /

 760 MHz IF integer frequency synthesizers
### 4.0 Application Schematic




DIMENSIONS (mm are the original dimensions)

| UNIT | $\mathbf{A}$ <br> max. | $\mathbf{A}_{\mathbf{1}}$ | $\mathbf{A}_{\mathbf{2}}$ | $\mathbf{b}$ | $\mathbf{b}_{\mathbf{1}}$ | $\mathbf{b}_{\mathbf{2}}$ | $\mathbf{b}_{\mathbf{3}}$ | $\mathbf{D}$ | $\mathbf{D}_{\mathbf{1}}$ | $\mathbf{E}$ | $\mathbf{E}_{\mathbf{1}}$ | $\mathbf{e}$ | $\mathbf{e}_{\mathbf{1}}$ | $\mathbf{e}_{\mathbf{2}}$ | $\mathbf{e}_{\mathbf{3}}$ | $\mathbf{e}_{\mathbf{4}}$ | $\mathbf{v}$ | $\mathbf{w}$ | $\mathbf{x}$ | $\mathbf{y}$ |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| mm | 0.80 | 0.10 | 0.70 | 0.35 | 0.50 | 0.50 | 0.50 | 4.1 | 2.2 <br> 2.05 <br> 0.60 | 4.1 <br> 3.9 | 2.2 <br> 2.0 | 0.5 | 3.2 | 3.2 | 3.15 | 3.15 | 0.2 | 0.15 | 0.15 | 0.05 |


| outline VERSION | REFERENCES |  |  | EUROPEAN PROJECTION | ISSUE DATE |
| :---: | :---: | :---: | :---: | :---: | :---: |
|  | IEC | JEDEC | EIAJ |  |  |
| SOT564-1 |  | MO-217 |  | $\square$ - | $\begin{aligned} & 00-02-01 \\ & 00-08-28 \end{aligned}$ |

# 2.5 GHz sigma delta fractional-N / 760 MHz IF integer frequency synthesizers 

## NOTES

### 2.5 GHz sigma delta fractional-N / 760 MHz IF integer frequency synthesizers

## Data sheet status

| Data sheet status ${ }^{[1]}$ | Product <br> status ${ }^{[2]}$ | Definitions |
| :--- | :--- | :--- |
| Objective data | Development | This data sheet contains data from the objective specification for product development. <br> Philips Semiconductors reserves the right to change the specification in any manner without notice. |
| Preliminary data | Qualification | This data sheet contains data from the preliminary specification. Supplementary data will be <br> published at a later date. Philips Semiconductors reserves the right to change the specification <br> without notice, in order to improve the design and supply the best possible product. |
| Product data | Production | This data sheet contains data from the product specification. Philips Semiconductors reserves the <br> right to make changes at any time in order to improve the design, manufacturing and supply. <br> Changes will be communicated according to the Customer Product/Process Change Notification <br> (CPCN) procedure SNW-SQ-650A. |

[1] Please consult the most recently issued data sheet before initiating or completing a design
[2] The product status of the device(s) described in this data sheet may have changed since this data sheet was published. The latest information is available on the Internet at URL http://www.semiconductors.philips.com.

## Definitions

Short-form specification - The data in a short-form specification is extracted from a full data sheet with the same type number and title. For detailed information see the relevant data sheet or data handbook.

Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 60134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.
Application information - Applications that are described herein for any of these products are for illustrative purposes only. Philips Semiconductors make no representation or warranty that such applications will be suitable for the specified use without further testing or modification.

## Disclaimers

Life support - These products are not designed for use in life support appliances, devices or systems where malfunction of these products can reasonably be expected to result in personal injury. Philips Semiconductors customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Philips Semiconductors for any damages resulting from such application.
Right to make changes - Philips Semiconductors reserves the right to make changes, without notice, in the products, including circuits, standard cells, and/or software, described or contained herein in order to improve design and/or performance. Philips Semiconductors assumes no responsibility or liability for the use of any of these products, conveys no license or title under any patent, copyright, or mask work right to these products, and makes no representations or warranties that these products are free from patent, copyright, or mask work right infringement, unless otherwise specified.

## Contact information

For additional information please visit
All rights reserved. Printed in U.S.A.
http://www.semiconductors.philips.com. Fax: +31 402724825
Date of release: 02-02
For sales offices addresses send e-mail to:
sales.addresses@www.semiconductors.philips.com.

